Adiabatic optical entanglement between electron spins in separate quantum dots

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We present an adiabatic scheme to entangle two electron spins localized in separate InAs/GaAs quantum dots via the distant Coulomb interaction between two similarly localized, optically-excited states. This mechanism can be used to perform two-qubit gates for quantum computation. Slowly-varying optical pulses minimize the pulse noise and the relaxation of the excited states. An analytic solution of the "dressed state" model gives a clear physical picture of the entangling processes, and a numerical solution for all the involved states is used to investigate the error dynamics. The results for two vertically-stacked quantum dots show that, for a broad range of dot parameters, a two-spin state with concurrence C > 0.85 can be obtained by four optical pulses with durations ~ 1 ns.

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Adiabatic passage uses slow variation of the system Hamiltonian to select a particular quantum path while avoiding unintended dynamics, and controlled adiabatic evolution of the ground state has been proposed as a model for quantum computation [1]. Stimulated Raman adiabatic passage (STIRAP) [2] allows the transfer of populations or coherences between quantum states through a "dark state" which efficiently suppresses relaxation. The addition of either an auxiliary qubit [3] or coherent control optical pulses [4, 5] to the STIRAP process allows one to construct a set of complete onequbit operations. In systems with a permanent interaction between qubits adiabatic passage through degenerate dressed states can also be used to construct two-qubit entangling gates [6]. However, for scalable solid-state quantum computation, it is important to keep the qubits isolated from each other except during gating. Electron spins in semiconductor quantum dots (QDs) are promising candidates for qubits [7]. They have long coherence time [8], can be manipulated by electric gates [9] or optically [10, 11, 12, 13, 14, 15, 16], and the coupling between the qubits can be induced externally, rather than permanently present.

In this Letter we show that the STIRAP strategy is well suited to the performance of two-qubit quantum operations with *uncoupled* electron spins in semiconductor QDs, with the entanglement arising from the Coulomb interaction of transient optically-excited states localized in the dots. As an illustration, we describe an entangling operation for two spins in separate self-assembled InAs/GaAs QDs. While for ease of understanding the entangling process is described in the path language, in fact, it represents a unitary transformation, i.e., a quantum operation, made up of a product of \sqrt{iSWAP} and controlled-phase gates. Combined with the single qubit rotations [4, 5] and optical initialization [15, 16], we obtain a set of gates for universal quantum computation. We employ the Voigt configuration (external magnetic field normal to the optical axis) to obtain the flexibility required to select the desired quantum paths through polarization and frequency selection. The evolution of system is then guided through a particular subset of quantum paths by a sequence of adiabatic pulses. In the dressed state picture the scheme can be viewed as an adiabatic passage of an arbitrary initial two-spin state through two long-lived states. The interference between the two paths results in an effective rotation in the spin subspace. In general, the method proposed here can be adapted to construct directly CPHASE and CNOT gates.

In two self-assembled InAs/GaAs QDs, the direct electron or hole tunnelling between the dots may be suppressed by selecting the dot heights and the interdot distance [13, 17]. Then, because the electrons and holes are confined differently, the intrinsic Coulomb coupling between particles in different dots modifies the optical transition energies [17, 18]. We employ this phenomenon to perform two-qubit operations. This is similar to the dipole blockade [19], but here we do not rely on an external electric field, and this makes the operation less sensitive to external noise, as compared Ref. [12] in which in-plane gates were used. The particular path used for the entangling operation is shown in Fig. 1(a). In the ideal case of strong Coulomb interaction, starting with the polarized state $|+,+\rangle$ one obtains the maximally entangled state $\frac{1}{\sqrt{2}}(|+,+\rangle+i|-,-\rangle)$ after an effective $\pi/2$ two-spin rotation. A longer excitation pulse results in coherent oscillations between $|+,+\rangle$ and $|-,-\rangle$ populations, which can be used as experimentally observable signature of the entanglement between the two spins.

Schematics of the pulse sequence and of the evolution of the appropriate dressed states are shown in Fig. 1(b,c). The long optical pulses utilized in the scheme may be generated by modulating cw lasers, which would provide sufficiently narrow frequency spectra of the pulses. Co-



FIG. 1: (Color online) (a) An optical scheme to control the entanglement between two spins in two InAs/GaAs QDs in the Voigt configuration. A two-spin state is denoted by a ket such as $|t+,+\rangle$ with $|\pm\rangle$ for the spin states and $|t\pm\rangle$ the trion states. Arrows indicate the linear polarizations V_j^{\pm} and H_j^{\pm} for the transitions $|\pm\rangle \leftrightarrow |t\pm\rangle$ and $|\pm\rangle \leftrightarrow |t\pm\rangle$ of dot j = 1, 2. (b) The time sequence of the polarized pulses operating on either dot. V(t) and H(t) are envelop functions for the optical pulses. For simplicity we use the same pulse shape, a rectangular pulse with smooth fronts shaped as $\sin^4(\pi t/T_f)$, for all pulses, and the same amplitudes for both V-pulses and for both H-pulses. (c) Adiabatic time evolution of the dressed state energies during the excitation. Solid lines show the essential energies which drive the operation.

herent optical coupling of the 5-state system shown in Fig. 1(a) does not yield a dark state, unlike in the familiar Λ system. However, the two states we use are long-lived under two-photon resonance [20] and we can further reduce trion relaxation by detuning the optical pulses and by adjusting their amplitudes.

For a single QD in the Voigt configuration with two single-electron spin states $|\pm\rangle = \frac{1}{\sqrt{2}}(e^{\dagger}_{\downarrow} \mp e^{\dagger}_{\uparrow})|0\rangle$, we consider only two lowest-energy negative-trion states $|t\pm\rangle = \frac{1}{\sqrt{2}}e^{\dagger}_{\downarrow}e^{\dagger}_{\uparrow}(h^{\dagger}_{\downarrow} \mp h^{\dagger}_{\uparrow})|0\rangle$, where the operators $e^{\dagger}_{\uparrow,\downarrow}$ and $h^{\dagger}_{\uparrow,\downarrow}$ create, respectively, an electron and a heavy hole with spin along or against the growth direction, which we also take as the optical axis. Because of the large confinement splitting, the heavy hole is weakly mixed with the light hole, and in any case, the effect of the mixing is easily accounted for by an adjustment of the axis of Rabi rotation between the trion and spin state [5]. With the above restriction, the system of two dots has 16 states. The four lowest energy spin states form the qubit sector. They are separated by the gap energy from eight singletrion states, which are similarly distant from four bi-trion states. The interdot Coulomb interaction of electrons and holes gives rise to a binding energy of the bi-trion,

$$\Delta = E_{1221}^{eeee} + E_{1221}^{hhhh} - E_{1221}^{ehhe} - E_{2112}^{ehhe}, \qquad (1)$$

where E_{jkkj}^{abba} is a two-particle Coulomb integral, e or h denoting electron or hole and j = 1, 2 the dots. In zero magnetic field, let the transition energy from the qubit sector to the single-trion sector be ω_{tj} . The single- to bi-trion transition energy is lowered by the binding energy Δ , thus enabling the two types of transitions to be independently addressed by different optical frequencies. Four optical fields can generate an effective coupling between the pairs of states $|+,-\rangle$ and $|-,+\rangle$ or between $|+,+\rangle$ and $|-,-\rangle$. In the following we use the latter pair because an efficient initialization of the state $|+,+\rangle$ is possible [16]. The proposed scheme can be applied to the other pair of states.

The quantum operation along the path between $|+,+\rangle$ and $|-,-\rangle$ involves five states and four optical fields (Fig. 1). The two H-polarized pulses create the interaction between two dots by optically coupling a bitrion to two trions in two dots. Then, the shorter Vpolarized pulses couple the qubit sector with the renormalized excited states and rotate the spins in a way similar to the single qubit operation [4, 5]. To avoid population excitation of the intermediate states, the optical fields are detuned by δ from resonance. The spinevolution operator is $U = \exp(-i\phi(1-\sigma_x)/2)$, where $\phi = \int \varepsilon(\tau) d\tau$ with $\varepsilon(t) = E_3(t)$ to be defined immediately below, and $\sigma_x = |+,+\rangle\langle-,-|+|-,-\rangle\langle+,+|$. An excitation with $\phi = \pi$ would create a maximally entangled state from either $|+,+\rangle$ or $|-,-\rangle$. The operation can be described in terms of dressed states, C_{1-5} . In the rotating wave and adiabatic approximations their energies are $E_1 = 0$, $E_{2,3} = \frac{1}{2}(\delta \pm \sqrt{\delta^2 + 4V(t)^2})$, and $E_{4,5} = \frac{1}{2}(\delta \pm \sqrt{\delta^2 + 4V(t)^2 + 8H(t)^2})$, sketched in Fig. 1(b,c). Adiabatic pulses do not excite transitions to the split-off energy levels $E_{2,4}$, and their states C_2, C_4 are ignored. The H-pulse lifts the degeneracy of $E_{1,3}$ and E_5 levels, but C_5 remains orthogonal to the spin subspace and the initial spin state is not transferred to it. Therefore, the transformation of a spin-state is controlled only by the evolution of the states C_1 and C_3 . In terms of the basis states shown in clockwise order in Fig. 1(a), these states are

$$\mathbf{C}_{1} = (V^{2} + 2H^{2})^{-1/2}[H, 0, -V, 0, H],
\mathbf{C}_{3} = (2V^{2} + 2\varepsilon^{2})^{-1/2}[-V, -\varepsilon, 0, \varepsilon, V],$$
(2)

with time dependencies understood. When the optical fields are switched off, \mathbf{C}_1 and \mathbf{C}_3 reduce to $\frac{1}{\sqrt{2}}[1,0,0,0,\pm 1]$ which belong to the spin sector, $\mathbf{C}_{2,4}$ to single-trion states, and \mathbf{C}_5 to $|t+,t-\rangle$. This constitutes the basic process to build entanglement and logic operations.

The operation is designed to minimize the effects of relaxation from excited states and pulse imperfections. The states \mathbf{C}_1 and \mathbf{C}_3 are long-lived because (i) \mathbf{C}_1 is orthogonal to the single-trions and \mathbf{C}_3 to the bi-trion, and (ii) the populations of their excited state components are controlled by the small parameters $(V/\delta)^2$ and $(V/H)^2$. Below we show that it is possible to maintain the total population of the excited states below 10% for pulse durations of the order of 1 ns. This makes the lifetime of \mathbf{C}_1 and \mathbf{C}_3 about 10 times longer than that of bare trions. For an arbitrary initial state, in addition to two-spin rotation described above, the $|+, -\rangle$ state acquires a phase $e^{-i\varphi}$, $\varphi = \frac{1}{2} \int [\delta - \sqrt{\delta^2 + 8V(\tau)^2}] d\tau$, driven by the V-fields coupling to the single trions $|t+, -\rangle$ and $|+, t-\rangle$. The resulting two-qubit gate is a product of conditional phase gates and a $\sqrt{i\text{SWAP}}$ gate.

Detuning the optical fields is required to avoid unintended dynamics, such as population transfer from $|+, -\rangle$ to the single trion states $|t+, -\rangle$ or $|+, t-\rangle$. As an aid to the design of this process, we gather in Fig. 2 all the transition energies on the same scale for both polarizations. The available input parameters are the energy levels from the dot fabrication, Δ from dot placement, the Zeeman splittings from the magnetic field, and the central frequencies of the optical pulses in the form of a single detuning frequency δ for simplicity. We arrive at a set of physically reasonable constraints in terms of



FIG. 2: (Color online) Energies of allowed optical transitions versus the optical frequencies (measured in energy units) for V-polarization (upper figure) and H-polarization (lower figure). The thin solid lines mark the transition energies in zero magnetic field. ω_{tj} is the transition energy between a spin state and a trion state in dot j. Their difference between the dots is shown as $\Delta \omega_t = \omega_{t2} - \omega_{t1}$. Δ is the bi-trion binding energy, thus making the transition energy between the single and bi-trion $\omega_{ti} - \Delta$. In a magnetic field, the electron and hole Zeeman splittings, $\omega_j^{\rm e}$ and $\omega_j^{\rm h}$ in dot j, cause the transition energy splitting, $2\Pi_j = \omega_j^{\rm e} + \omega_j^{\rm h}$ in the V-polarization and $2\Sigma_i = \omega_i^{\rm e} - \omega_i^{\rm h}$ in the H-polarization. The Zeeman splitted transitions used in the quantum operation and offresonant transitions are denoted by the thick solid lines and thick dashed lines respectively. The vertical arrows show the central frequencies of the optical pulses and their detuning δ from the corresponding transitions.



FIG. 3: (Color online) Concurrence of the output two-spin state for different values of the bi-trion binding energy. Excitation parameters: filled circles $-\delta = -0.1$ meV, $V_0 =$ 20 meV, $H_0 = 44$ meV; open squares $-\delta = -0.13$ meV, $V_0 = 20$ meV, $H_0 = 44$ meV; filled squares $-\delta = -0.1$ meV, $V_0 = 10$ meV, $H_0 = 44$ meV; open triangles $-\delta = 0.12$ meV, $V_0 = 15$ meV, $H_0 = 65$ meV. V_0 and H_0 denote amplitudes of the V- and H-polarized fields. Inset: fidelity of the analytical model compared to numerical simulations as a function of Δ .

the energies of Fig. 2: $\Delta \omega_t \gg \Delta \gg \Pi_i, \Sigma_i \gg \delta$. If the bi-trion binding energy Δ and the Zeeman splittings Π_i and Σ_i are comparable to the detuning δ , the off-resonant processes have the undesired effect that the same pulse sequence which excites the desired quantum path also excites, albeit off-resonantly, an path involving the single trion states $|+, t-\rangle$ and $|t+, -\rangle$, and this tends to reduce the two-spin rotation angle. This secondary process can be investigated with a 5-level model similar to that of the resonant path. All other off-resonant excitations just give rise to phases in second-order perturbation. Including these effects, the resultant operation, can thus be factorized as a product of control phase gates and a \sqrt{iSWAP} gate.

To examine the effects of trion relaxation and offresonant pumping, we numerically integrate the equation of motion for the 16-level density matrix including all the allowed transitions of Fig. 2. In particular, we consider two vertically stacked self-assembled InAs QDs. The trion relaxation term in our model is expressed in the Lindblad form [15] assuming that all the jumps between the levels are independent and the relaxation rates for both dots are the same, $\Gamma = 1.2 \ \mu eV$ [14]. The recombination rate of an electron and hole located in different dots and their spin decoherence [8] are negligible on the operation timescale. The interdot difference of the two single-trion energies is taken to be $\Delta \omega_t = 10$ meV. The electron and hole g-factors are the same for both dots and equal $g_{\rm e} = -0.48, g_{\rm h} = -0.31$ [16]. There appears to be no experimental data on the bi-trion binding energy in the literature. Gerardot et al. have obtained 4.56 meV for binding energy of two excitons located in the dots with the vertical separation 4.5 nm [17]. Scheibner et al. [18] have measured -0.3 meV for the shift of a negative trion transition when a second dot is occupied by a hole with respect to a bare transition (interdot distance is 6 nm). These give us two disparate values for the biexciton binding energy. From a simple analytical model [21] we estimate $\Delta = 0.8$ meV for two dots with the vertical separation 8 nm. To characterize the entanglement of the output state we use the concurrence, C, [22] for the reduced density matrix of the qubit sector.

The most crucial parameter of the operation is the bitrion binding energy Δ . Figure 3 shows the calculated concurrence of the entangled output state as a function of Δ for several sets of excitation parameters. The laser fields are weak enough to avoid unintentional dynamics outside the 16-level system (not studied here). We find that a state with a concurrence C > 0.85 can be generated if $\Delta > 0.3$ meV for a broad range of excitation parameters. For smaller values of Δ the concurrence is strongly dependent on the material parameters, and the excitation scheme has to be designed more carefully. The inset of Fig. 3 shows the fidelity of the analytical model using the numerical simulations as standard, and it is clear that the analytical model describes fairly well the dynamics of the system in the same range of Δ . An example of the two-qubit evolution is given in Fig. 4, where pulses has been optimized to obtain a final state with a maximal entanglement from $|+,+\rangle$. The concurrence of the final state $C \approx 0.87$ is limited by relaxation from the single- and bi-trion states. Longer excitation pulses result in Rabi oscillations of the pseudo-spin shown in Fig. 4(b). The entangling operation is weakly sensitive to the trion relaxation rate. Doubling the spontaneous photon emission rate results in less than 10% variation of the concurrence. To measure the entanglement of the prepared state requires a full state tomography [23]. A partial indication of the entanglement is the oscillations between the $|+,+\rangle$ and $|-,-\rangle$ states, Fig. 4(b). It can also be probed by exciting resonantly the population of a given two-spin state to a double trion state and then measuring two-photon cross correlations [17].

In conclusion, we have developed an adiabatic approach for the optical control of entanglement between two electron spins in semiconductor self-assembled quantum dots. We use the Voigt configuration of the external magnetic field. Our excitation scheme, utilizing the Coulomb interaction between trions, is insensitive to the material parameters, pulse imperfections and relaxation from the trion states. We show that using four optical fields a two-spin entangled state with the concurrence C > 0.85 can be created on the timescale of the order of 1 nanosecond. With refinement, this scheme may be used as a two-qubit gate for quantum computation.

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FIG. 4: (Color online) Evolution of the $|+,+\rangle$ spin state controlled by four optical fields. The Coulomb coupling is $\Delta = 0.3$ meV, the detuning is $\delta = -0.1$ meV, the magnetic field is B = 8 T and the pulse amplitudes are $V_0 = 20 \ \mu eV$ and $H_0 = 44 \ \mu eV$. Durations of the H- and V-polarized pulses related to each other as $T_H = T_V + 2T_f$, where $T_f = 250$ ps is the front duration. (a) Dynamics of the qubit sector controlled by four optical pulses at time t = 0, $T_V = 340$ ps. (b) Spin density matrix as a function of T_V .

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- [1] E. Farhi et al., Science, **292**, 472 (2001).
- J. Oreg, F. T. Hioe, and J. H. Eberly, Phys. Rev. A 29, 690 (1984); K. Bergmann, H. Theuer, B. W. Shore, Rev. Mod. Phys. 70, 1003 (1998).
- [3] Z. Kis and F. Renzoni, Phys. Rev. A 65, 032318 (2002).
- [4] Pochung Chen et al., Phys. Rev. B 69, 075320 (2004).
- [5] C. Emary and L. J. Sham, J. Phys.: Condens. Matter 19, 056203 (2007).
- [6] R. G. Unanyan, B. W. Shore, and K. Bergmann, Phys. Rev. A 63, 043405 (2001).
- [7] D. Loss and D. P. DiVincenzo, Phys. Rev. A 57, 120 (1998).
- [8] A. Greilich et al., Science **313**, 341 (2006).
- [9] J. R. Petta et al., Science **309**, 2180 (2005); F. H. L. Koppens et al., Nature **442**, 766 (2006).
- [10] A. Imamoglu et al., Phys. Rev. Lett. 83, 4204 (1999).
- [11] C. Piermarocchi et al., Phys. Rev. Lett. 89, 167402 (2002).
- [12] T. Calarco et al., Phys. Rev. A 68, 012310 (2003).
- [13] C. Emary and L. J. Sham, Phys. Rev. B 75, 125317 (2007).
- [14] M. Atatüre et al., Science **312**, 551 (2006).
- [15] C. Emary et al., Phys. Rev. Lett. 98, 047401 (2007).
- [16] Xiaodong Xu et al., Phys. Rev. Lett. 99, 097401 (2007).
- [17] B. D. Gerardot et al., Phys. Rev. Lett. 95, 137403 (2005).
- [18] M. Scheibner et al., Phys. Rev. Lett. 99, 197402 (2007).
- [19] D. Jaksch et al., Phys. Rev. Lett. 85, 2208 (2000).
- [20] F. T. Hioe and C. E. Carroll, Phys. Rev. A, 37 3000 (1988).
- [21] R. J. Warburton et al., Phys. Rev. B 58, 16221 (1998).
- [22] W. K. Wootters, Phys. Rev. Lett. 80, 2245 (1998).
- [23] C. F. Roos et al., Phys. Rev. Lett. 92, 220402 (2004).